NSN 5961-01-165-5164

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-165-5164 **Inclosure Material:** Plastic **Overall Length:** Between 0.285 inches and 0.375 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.188 inches and 0.250 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-201ad **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage and 420.0 reverse voltage, total rms **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute and 100.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: